

SEP 11 2006

Atty. Dkt. No. 039153-0649 (H0982)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Xiang et al.  
Title: FULLY DEPLETED STRAINED  
SEMICONDUCTOR ON  
INSULATOR TRANSISTOR  
AND METHOD OF MAKING  
THE SAME  
Appl. No.: 10/773,026  
Filing Date: 02/05/2004  
Examiner: Doty, Heather Anne  
Art Unit: 2813  
Conf. No.: 6093

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| <p><b>CERTIFICATE OF FACSIMILE TRANSMISSION</b><br/>I hereby certify that this paper is being facsimile transmitted to the<br/>United States Patent and Trademark Office, Alexandria, Virginia<br/>on the date below.</p> <p>Carolyn Simpson<br/>(Printed Name)</p> <p><i>Carolyn Simpson</i><br/>(Signature)</p> <p>September 11, 2006<br/>(Date of Deposit)</p> |
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**AMENDMENT AND REPLY UNDER 37 CFR 1.111**

Mail Stop AMENDMENT  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

This communication is responsive to the Non-Final Office Action dated May 11, 2006,  
concerning the above-referenced patent application.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2  
of this document.

**Remarks/Arguments** begin on page 6 of this document.

Please amend the application as follows: